

SANYO Semiconductors DATA SHEET

SBS813 — Low VF Schottky Barrier Diode 30V, 3.0A Rectifier

Applications

· High frequency rectification (switching regulators, converters, choppers).

Features

- · Small switching noise.
- Low forward voltage (I_F=3A, V_F max=0.42V).
- · Ultrasmall package permitting applied sets to be small and slim.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	VRRM		30	V
Nonrepetitive Peak Reverse Surge Voltage	VRSM		30	V
Average Output Current	lo		3.0	Α
Surge Forward Current	IFSM	50Hz sine wave, 1 cycle	20	Α
Junction Temperature	Tj		-55 to +125	°C
Storage Temperature	Tstg		-55 to +125	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onit
Reverse Voltage	VR	IR=2.0mA	30			V
Forward Voltage	VF	IF=2.0A		0.335	0.385	V
		IF=3.0A		0.37	0.42	V
Reverse Current	IR	V _R =15V			1.4	mA
Interterminal Capacitance	С	V _R =10V, f=1MHz		90		pF
Reverse Recovery Time	t _{rr}	I _F =I _R =100mA, See specified Test Circuit.			20	ns
Thermal Resistance	Rth(j-a)	Mouted on a ceramic board (1200mm²X0.8mm)		50		°C / W

Marking: SF

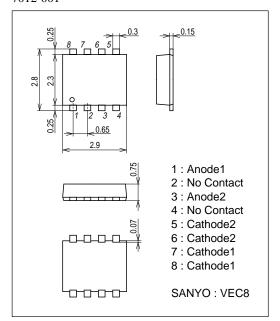
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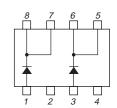
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

Package Dimensions

unit : mm 7012-001

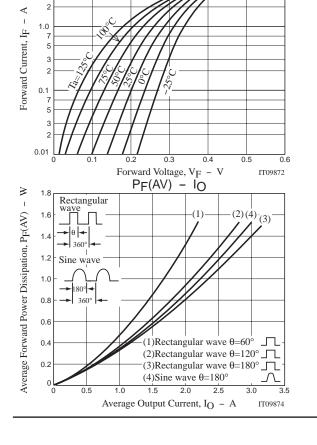


Electrical Connection

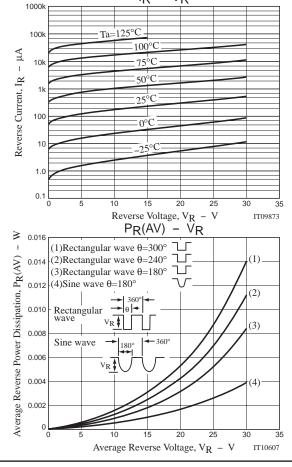


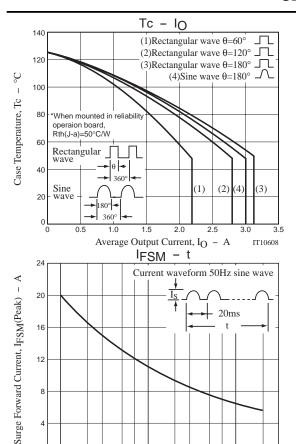
- 1 : Anode1
- 2 : No Contact
- 3 : Anode2
- 4 : No Contact 5 : Cathode2
- 6 : Cathode2
- 7 : Cathode1
- 8 : Cathode1

Top view

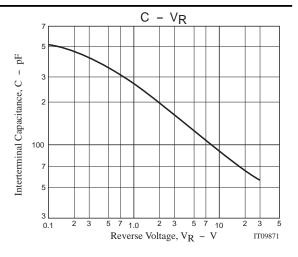


IF - VF





0.1 ² Time t = s



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